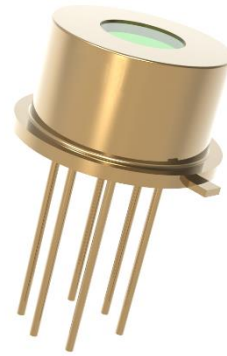


InGaAs APD Module

Model: OPR1000-1550-30-Z

Features

- Sensitivity: $\geq 500\text{kV/W}$
- Bandwidth: 70Mhz
- InGaAs APD: 900 to 1700nm
- Low noise
- High reliability
- TO39 package with flat window



Applications

- LIDAR
- Laser finding
- Free space optical communication

Absolute Maximum Ratings

Parameter	Unit	Symbol	Rating
Reverse breakdown voltage	V	V_R	V_{BR}
Operating temperature	$^{\circ}\text{C}$	T_C	-40~+85
Storage temperature	$^{\circ}\text{C}$	T_{STG}	-55~+100
Maximum optical input power	mW	P_{in}	100
Module mains voltage	V	V_{cc}/V_{EE}	± 5
Power dissipation	mW	P_w	250
Soldering temperature(time)	$^{\circ}\text{C}$	-	300 (10s)

Optical/Electrical Characteristics ($T=25^{\circ}\text{C}$, unless otherwise stated)

Parameter	Symbol	Value			Unit	Test conditions
		Min.	Typ.	Max.		
Response Spectrum	λ	900~1700			nm	
Active Diameter	D		1000		μm	
Reverse breakdown voltage	V_{BR}	30		70	V	
Operating voltage	V_R	V_R-3			V	M=10
Responsivity	R_V	500			kV/W	M=10,1.55 μm @ $\tau=100\text{ns}$
Dynamic range	DY	25			dB	M=10,1.55 μm @ $\tau=100\text{ns}$
-3dB bandwidth	BW		30		Mhz	M=10,1.55 μm @ $\tau=100\text{ns}$
Rise/Fall time	t_r		11.6		ns	M=10,1.55 μm @ $\tau=100\text{ns}$

Noise Equivalent Power	NEP		150		fW/ $\sqrt{\text{Hz}}$	M=10,f=100kHz, $\Delta=1\text{hz}$
Output impedance	R_O		50		Ω	
Output Voltage Swing	V_O	0.7			V	
Positive Supply Current	I_{CC}			30	mA	
Negative Supply Current	I_{EE}			10	mA	50 Ω Load
Temperature coefficient of V_{op} for constant gain	γ	0.06	0.12	0.16	V/ $^{\circ}\text{C}$	-45 $^{\circ}\text{C}$ ~ +85 $^{\circ}\text{C}$
Concentricity	ΔD			30	μm	

Schematic Block Diagram

